RIVILA3565-58供应商 RIVILA3565-58

Wideband Low Noise MMIC Amplifier

PRODUCT INFORMATION

Description

The Raytheon RMLA3565-58 is a single bias wideband low noise MMIC amplifier that meets the following specifications over the 3.5 - 6.5 GHz frequency range. The MMIC requires no external matching circuits no external gate bias supply. This device uses Raytheon's advanced 0.25 µm PHEMT process to provide low noise, high linearity and low current.

Features

- 19.0 dB Gain Typical
- 1.5 dB Noise Figure, Typical 5.0 6.5 GHz
- Single Positive Bias
- Small Outline Metal Base Quad Plastic Package
- Internal 50Ω Matching



Absolute Maximum Ratings1

| The state of the s | | | |
|--|---------|------------|------|
| Parameter | Symbol | Value | Unit |
| Positive Drain DC Voltage (No RF) | Vdd | 6.5 | V |
| RF Input Power (from 50Ω source) | Pin(CW) | 0 | dBm |
| Drain Current | ldd | 130 | mA |
| Case Operating Temperature | Tc | -35 to 85 | °C |
| Storage Temperature Range | Tstg | -40 to 110 | °C |
| Soldering Temperature | Tsolder | 220 | °C |

Electrical Characteristics²

| Parameter | Min | Тур | Max | Unit |
|---|------|--------------------|-----|----------|
| Frequency Range | 3.5 | - 14 | 6.5 | GHz |
| Gain (Small Signal)3,4 | 17.0 | 19.0 | | dB |
| Gain Variation vs Temp | | -0.008 | | dB/°C |
| Noise Figure ⁴ 3.5 - 5 GHz 5 - 6.5 GHz Power Out, P1dB @ 5.5 GHz | 8.0 | 1.4 1.5 10.0 | 2.2 | dB dB |
| | | | | |

| Parameter | Min | Тур | Max | Unit |
|---|------|-------|------|------|
| OIP3 @ 5.5 GHz, +3 dBm Pout total | 17 | 21.0 | | dBm |
| Idd | | 70.0 | 85.0 | mA |
| Vdd | 3.0 | 4.0 | 6.0 | V |
| Input Return Loss | | -15.0 | | dB |
| Output Return Loss | - 17 | -10.0 | | dB |
| Thermal Resistance Rjc (Channel to Case) | ZSC | 135 | | °C/W |

- 1. No permanent damage with only one parameter set at maximum limit and all other parameters at typical conditions
- 2. All parameters met at Tc = +25 °C, Vdd = 4.0V
- 3. Pin = -20 dBm, Vdd = 4.0 V, Frequency 3.5 6.5 GHz
- 4. Data de-embedded from fixture loss

Characteristic performance data and specifications are subject to change without notice.



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Application Information

CAUTION: THIS IS AN ESD SENSITIVE DEVICE

The following briefly describes a procedure for evaluating the high efficiency PHEMT amplifier packaged in a surface mount package. It may be noted that the chip is a fully monolithic single ended two stage amplifier for 3.5 to 6.5 GHz applications.

Test Fixture

Figure 1 shows the outline and pin-out descriptions for the packaged device. Figure 2 shows the functional block diagram of the packaged product. A typical test fixture schematic showing external bias components is shown in figure 3. Figure 4 shows typical layout of an evaluation board corresponding to the schematic diagram. A typical performance obtained from the test fixture is shown in figure 5. The following should be noted:

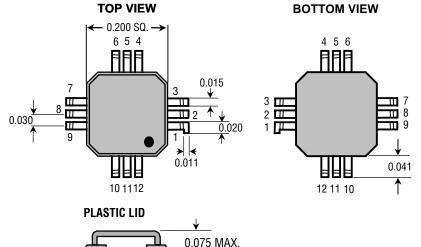
- (1) Package pin designations are as shown in figure 1.
- (2) Vd is the Drain Voltage (positive) applied at the pins of the package
- (3) Vdd is the positive supply voltage at the evaluation board terminal

Figure 1
Package Outline and
Pin Designations

Dimensions in inches

0.008 0.015

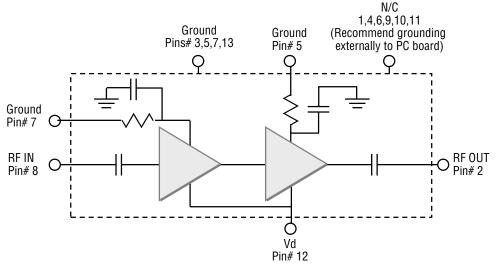
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SIDE SECTION

| Pin# | Description | |
|------|-----------------------|--|
| 1 | N/C | |
| 2 | RF Out | |
| 3 | GND | |
| 4 | N/C | |
| 5 | GND | |
| 6 | N/C | |
| 7 | GND | |
| 8 | RF In | |
| 9 | N/C | |
| 10 | N/C | |
| 11 | N/C | |
| 12 | Vd | |
| 13 | GND (Package Base) | |

Figure 2
Functional Block
Diagram



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Figure 3 Schematic for a Typical Test Evaluation Board (RMLA3565-58-TB)

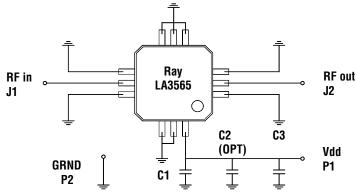
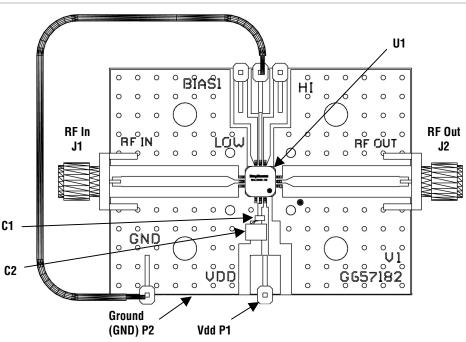


Figure 4 Layout and Assembly of Test Evaluation Board (RMLA3565-58-TB)



Test Procedure

The following sequence of procedure must be followed to properly test the power amplifier:

for the evaluation board (RMLA3565-58-TB)

Step 1: Turn off RF input power.

Step 2: Use GND terminal of the evaluation board for

DC supplies.

Step 3: Apply drain supply voltages of +4.0 V to

evaluation board terminal Vdd.

Step 4: After the bias condition is established, RF input

signal may now be applied.

Step 5: Follow turn-off sequence of:

(i) Turn off RF Input Power

(ii) Turn down and off Vdd

Parts List

for Test Evaluation Board (RMLA3565-58-TB)

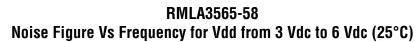
| Part | Value | EIA Size | Vendor(s) |
|--------|----------------|-------------------|----------------------------|
| C1 | 330 pF | .04" x .02" | AVX, Murata, Novacap, |
| C2 | 4.75 uF | .14"x .11" | Sprague, ATC, AVX, Murata, |
| U1 | RMLA3565-58 | .28" x .28" x .07 | Raytheon |
| P1, P2 | Terminal | | Samtec |
| J1, J2 | SMA Connectors | | E.F. Johnson |
| Board | R04003(Rogers) | 1.99x1.50x.032 | Raytheon |

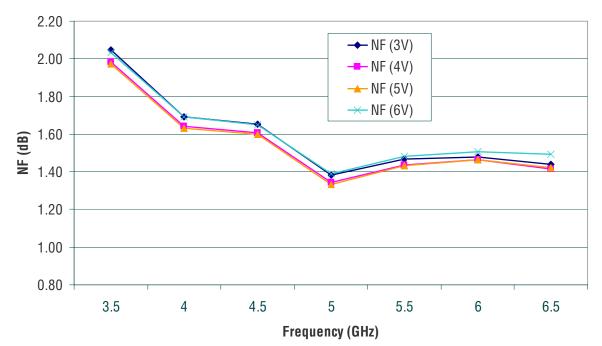
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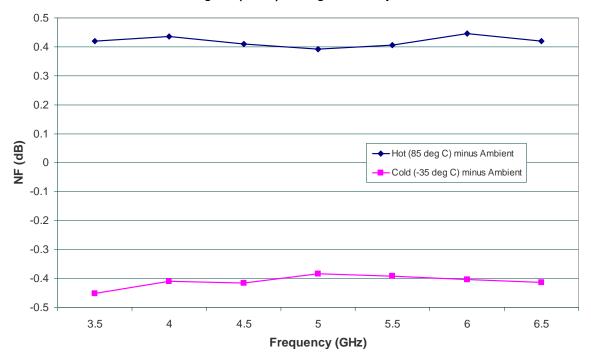
PRODUCT INFORMATION

Performance Data





RMLA3565-58
Noise Figure (4Vdc) Change Vs Temperature

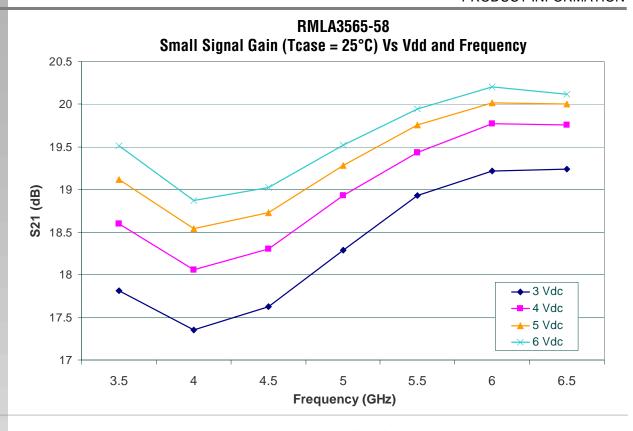


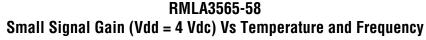
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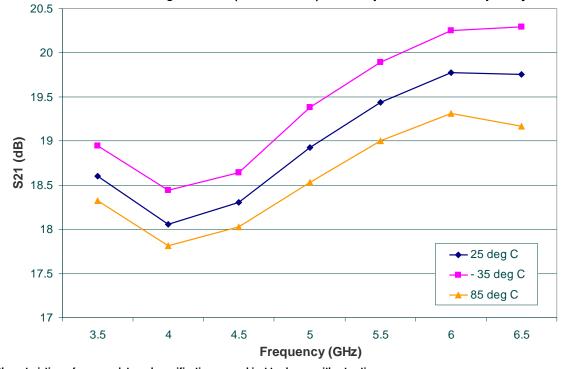
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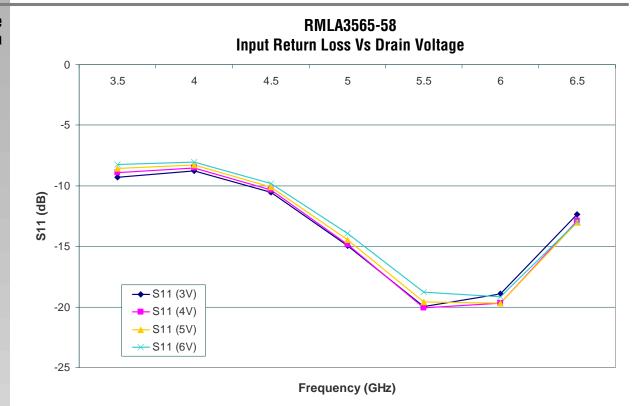


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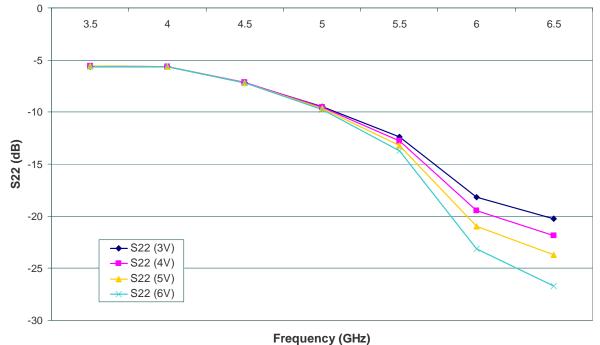
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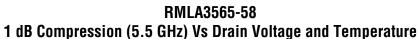
www.ravtheonrf.com

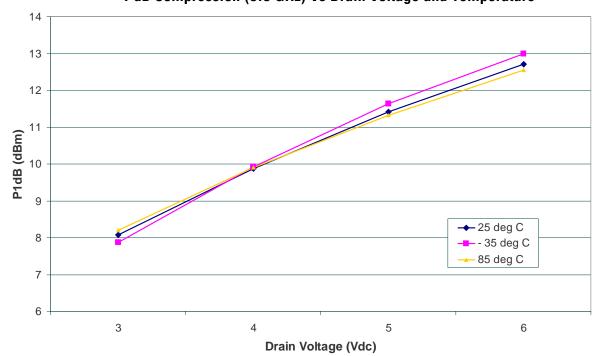
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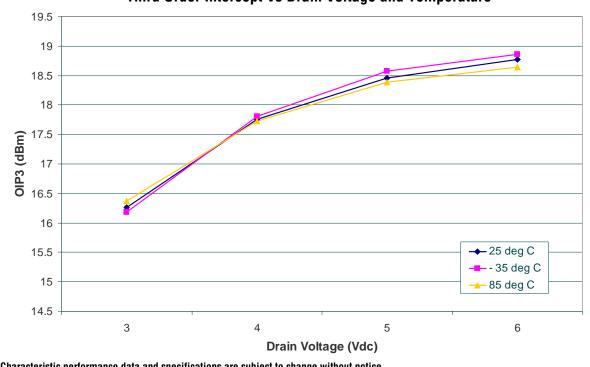
Raytheon RF Components

Performance Data





RMLA3565-58
Third Order Intercept Vs Drain Voltage and Temperature



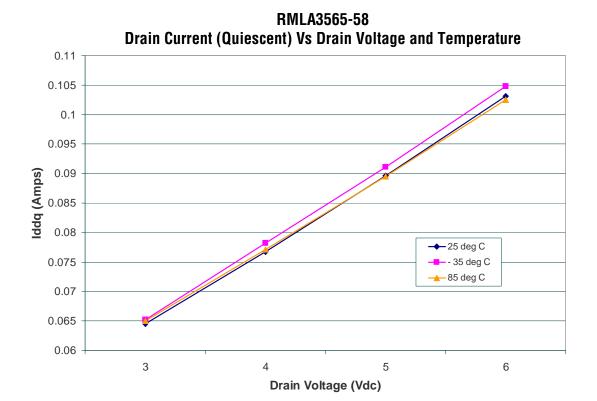
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